AMENDMENTS TO THE CLAIMS

Please amend claims 1, 4, 10-12, 14, 15, 19, 21, 22 and 24 as follows.

Please cancel claims 3, 13, 16, 17 and 20 without prejudice.

1. (Currently amended) An apparatus, comprising:

an electrode including a tapered end, wherein the tapered end has an angle between

approximately five and thirty degrees; and

a piezoelectric material of an acoustic resonator disposed over the electrode.

2. (Original) The apparatus of claim 1 wherein the piezoelectric material comprises

Aluminum Nitride (AlN), Zinc Oxide (ZnO), or lead titanate zirconate (PZT).

3. (Cancelled)

4. (Currently amended) The apparatus of claim 1 wherein the electrode comprises at

least one of aluminum, gold, chromium, platinum, and molybdenum.

5. (Original) The apparatus of claim 1, further comprising a top electrode adjacent to a

second side of the piezoelectric material, wherein the electrode is a bottom electrode adjacent

to a first side of the piezoelectric material.

Atty Docket: 42.P16637

Serial No. 10/607,764

Reply to Office Action of Dec. 7, 2004

Examiner: Tan Art Unit: 2819

- 2 -

6. (Original) The apparatus of claim 5, further comprising a substrate layer under the

bottom electrode.

7. (Original) The apparatus of claim 6, further comprising a dielectric layer between the

substrate layer and the bottom electrode.

8. (Original) The apparatus of claim 1 wherein the tapered end is formed through a wet

etching process.

9. (Original) The apparatus of claim 1 wherein the acoustic resonator is a film bulk

acoustic resonator (FBAR).

10. (Currently amended) A film bulk acoustic resonator (FBAR), comprising:

a bottom electrode including a tapered end;

a piezoelectric layer layered on the bottom electrode, wherein a surface area of the

bottom electrode is less than a surface area of the piezoelectric layer; and

a top electrode positioned on top of the piezoelectric layer wherein at least a portion

of the piezoelectric layer is disposed between the bottom electrode and the top electrode.

11. (Currently amended) The apparatus FBAR of claim 10, further comprising a

substrate positioned under the bottom electrode.

Atty Docket: 42.P16637

Serial No. 10/607,764

Examiner: Tan Art Unit: 2819

- 3 -

12. (Currently amended) The apparatus <u>FBAR</u> of claim 10 wherein the tapered end has an angle between approximately five and thirty degrees between a flat bottom side of the tapered end and a sloped upper side of the tapered end.

13. (Cancelled)

14. (Currently amended) The apparatus <u>FBAR</u> of claim <u>13 10</u> wherein at least a portion of a parameter of the bottom electrode includes the tapered end.

15. (Currently amended) A method, comprising:

forming a metal layer on top of a dielectric layer; and

placing a photoresist layer on top of the metal layer; and

shaping the metal layer to form a tapered electrode of an acoustic resonator, wherein shaping the metal layer comprises wet etching the metal layer to form the tapered electrode.

16. (Cancelled)

17. (Cancelled)

18. (Original) The method of claim 15 wherein the tapered electrode has an angle between approximately five and thirty degrees.

Atty Docket: 42.P16637 Serial No. 10/607,764

Reply to Office Action of Dec. 7, 2004

19. (Currently amended) An apparatus, comprising:

a piezoelectric layer of an acoustic resonator; and

means for preventing cracks in the piezoelectric layer, wherein the means for

preventing cracks comprises a bottom electrode including a tapered end positioned under the

piezoelectric layer.

20. (Cancelled)

21. (Currently amended) The apparatus of claim 20 19 wherein the tapered end has an

angle between approximately five and thirty degrees.

22. (Currently amended) The apparatus of claim 20 19 wherein the acoustic resonator is a

film bulk acoustic resonator (FBAR).

23. (Original) The apparatus of claim 22 wherein the piezoelectric layer comprises

Aluminum Nitride (AlN), Zinc Oxide (ZnO), or lead titanate zirconate (PZT).

24. (Currently amended) A system, comprising:

a film bulk acoustic resonator (FBAR) filter, comprising:

a bottom electrode including a tapered end, wherein the tapered end

has an angle between approximately five and thirty degrees; and

- 5 -

a piezoelectric material layered on the bottom electrode; and

a transmitter electrically coupled to the FBAR filter.

Atty Docket: 42.P16637 Serial No. 10/607,764

Reply to Office Action of Dec. 7, 2004

Examiner: Tan

Art Unit: 2819

- 25. (Original) The system of claim 24 wherein the piezoelectric material comprises Aluminum Nitride (AlN), Zinc Oxide (ZnO), or lead titanate zirconate (PZT).
- 26. (Original) The system of claim 24 wherein the system is a wireless device.

Atty Docket: 42.P16637 Serial No. 10/607,764

Reply to Office Action of Dec. 7, 2004